

Single Phase Rectifier Bridge

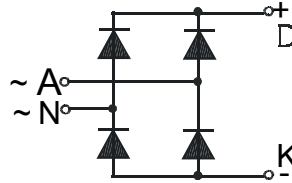
PSB 19F

$I_{dAV} = 19 \text{ A}$
 $V_{RRM} = 800 - 1200 \text{ V}$
 $t_{rr} = 40 \text{ ns}$

with fast Recovery Epitaxial Diode (FRED)

Preliminary Data Sheet

V_{RSM}	V_{RRM}	Type
V_{DSM}	V_{DRM}	
(V)	(V)	
800	800	PSB 19F/08
1200	1200	PSB 19F/12



Symbol	Test Conditions	Maximum Ratings
I_{dAV}^*	$T_C = 85 \text{ }^\circ\text{C}$, (per module)	19 A
I_{dAVM}		90 A
I_{FSM}	$T_{VJ} = 45 \text{ }^\circ\text{C}$ t = 10 ms (50 Hz), sine	40 A
	$V_R = 0$ t = 8.3 ms (60 Hz), sine	45 A
	$T_{VJ} = T_{VJM}$ t = 10 ms (50 Hz), sine	35 A
	$V_R = 0$ t = 8.3 ms (60 Hz), sine	40 A
$\int i^2 dt$	$T_{VJ} = 45 \text{ }^\circ\text{C}$ t = 10 ms (50 Hz), sine	10 A ² s
	$V_R = 0$ t = 8.3 ms (60 Hz), sine	10 A ² s
	$T_{VJ} = T_{VJM}$ t = 10 ms (50 Hz), sine	5 A ² s
	$V_R = 0$ t = 8.3 ms (60 Hz), sine	5 A ² s
T_{VJ}		-40... + 150 °C
T_{VJM}		150 °C
T_{stg}		-40... + 125 °C
V_{ISOL}	50/60 Hz, RMS t = 1 min	3000 V~
	$I_{ISOL} \leq 1 \text{ mA}$ t = 1 s	3600 V~
M_d	Mounting torque (M4)	1.5 - 1.8 Nm
		14 - 16 lb.in.
Weight	typ.	16 g

Symbol	Test Conditions	Characteristic Value
I_R	$V_R = V_{RRM}, T_{VJ} = T_{VJM}$	$\leq 0.25 \text{ mA}$
	$V_R = V_{RRM}, T_{VJ} = 25 \text{ }^\circ\text{C}$	$\leq 0.06 \text{ mA}$
V_F	$I_F = 10 \text{ A}, T_{VJ} = 25 \text{ }^\circ\text{C}$	$\leq 2.92 \text{ V}$
V_{TO}	For power-loss calculations only	1.32 V
r_T		30 mΩ
R_{thJC}	per diode; DC	2.5 K/W
	per module	0.63 K/W
R_{thJK}	per diode; DC	2.8 K/W
	per module	0.7 K/W
I_{RM}	$I_F = 12 \text{ A}; -di_F/dt = 100 \text{ A}/\mu\text{s}; V_R = 100 \text{ V}$ $L = 0.05 \text{ mH}; T_{VJ} = 100 \text{ }^\circ\text{C}$	typ. 4 A
t_{rr}	$I_F = 1 \text{ A}; -di_F/dt = 50 \text{ A}/\mu\text{s}; V_R = 30 \text{ V};$ $T_{VJ} = 25 \text{ }^\circ\text{C}$	typ. 40 ns
d_s	Creeping distance on surface	11.2 mm
d_A	Creeping distance in air	9.7 mm
a	Max. allowable acceleration	50 m/s ²

Data according to IEC 60747 refer to a single diode unless otherwise stated
*- for resistive load at bridge output

Features

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- Package with DCB ceramic base plate
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering
- UL registered, E 148688

Applications

- Supplies for DC power equipment
- Input and output rectifier for high frequency
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Low noise switching
- Small and light weight

Package style and outline

Dimensions in mm (1mm = 0.0394")

